Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	3161	257/204.ccls. 257/206.ccls. 257/351.ccls. 257/369.ccls. 257/390.ccls. 257/903.ccls.	US-PGPUB; USPAT	OR	OFF	2004/12/06 16:06
L2	848	1 and (sram (static near4 memory) (memory with cell with six with transistor))	US-PGPUB; USPAT	OR	OFF	2004/12/06 16:08
L3	80	1 and (sram (static near4 memory)) and (memory with cell with six with transistor)	US-PGPUB; USPAT	ÒR	OFF	2004/12/06 16:10
L4	106	1 and (sram (static near4 memory)) and ((memory with cell with six with transistor) "6T")	US-PGPUB; USPAT	OR	OFF	2004/12/06 16:58
L5	184	1 and (sram (static near4 memory)) and ((memory with cell with six with transistor) "6T")	US-PGPUB; USPAT	OR	ON	2004/12/06 17:00
L6	622	(sram (static near4 memory)) same ((memory with cell with (six "6") with transistor) "6T") same (cmos nmos pmos complementary)	US-PGPUB; USPAT	OR	ON	2004/12/06 17:03
L7	174	6 same gate	US-PGPUB; USPAT	OR	ON	2004/12/06 17:02
L8 .	34	(sram (static near4 memory)) and ((memory with cell with (six "6") with transistor) "6T") and (cmos nmos pmos complementary)	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 17:04
L9	164	(sram (static near4 memory) cmos nmos pmos complementary) and ((memory with cell with (six "6") with transistor) "6T")	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/06 17:05
S1	1	"5930163".pn.	US-PGPUB; USPAT	OR	OFF	2004/12/06 16:05
S2	3	jp-10178110-\$.did. 2003jp-0121630.ap,prai.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/29 11:54